Acene Ring Size Optimization in Fused Lactam Polymers
Enabling High n-Type Organic Thermoelectric Performance

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Abstract

Three n-type fused lactam semiconducting polymers were synthesized for thermoelectric and transistor applications via a cheap, highly atom-efficient and non-toxic transition-metal free aldol polycondensation. Energy level analysis of the three polymers demonstrated that reducing the central acene core size from two anthracene (A-A), to mixed naphthalene-anthracene (A-N) and two naphthalene cores (N-N) resulted in progressively larger electron affinities, thereby leading to an increasingly more favorable and efficient solution doping process when employing 4-(2,3-dihydro-1,3-dimethyl-1H-benzimidazol-2-yl)-N,N-dimethylbenzenamine (N-DMBI) as the dopant. Meanwhile, organic field effect transistor (OFET) mobility data showed the N-N and A-N polymers to feature the highest charge carrier mobilities, further highlighting the benefits of aryl core contraction to the electronic performance of the materials. Ultimately, the combination of these two factors resulted in N-N, A-N and A-A to display power factors (PF) of 3.2 μW m⁻¹ K⁻², 1.6 μW m⁻¹ K⁻² and 0.3 μW m⁻¹ K⁻² respectively when doped with N-DMBI, whereby the PF recorded for N-N and A-N are amongst the highest reported in the literature for n-type polymers. Importantly, the results reported in this study highlight that modulating the size of the central acene ring is a highly effective molecular design strategy to optimize the thermoelectric performance of conjugated polymers thus also providing new insights into the molecular design guidelines for the next generation of high-performance n-type materials for thermoelectric applications.

Introduction

With the continuously growing demand for energy and the need to reduce greenhouse gas emissions it is imperative to develop sustainable and environmentally friendly energy solutions to effectively combat global warming. Given the ubiquity of waste heat produced from industrial processes, thermoelectric generators capable of converting thermal gradients into electrical energy are a promising option to contribute solving the energy issues faced in
the 21st century. Thermoelectric generators are particularly attractive since they do not contain any moving mechanical components, thus reducing wear and improving the durability of devices. Moreover, their facile scalability should enable their applicability to a range of systems, including sensors, electronic components for the internet of things (IoT) and wearable electronics. Although the vast majority of thermoelectric research has been focused on inorganic materials, their organic counterparts display several advantages, including: (i) their compatibility with solution-based processing and low-cost roll-to-roll printing techniques; (ii) their reduced toxicity; (iii) their lightweight and flexible nature; (iv) the significantly higher abundance and lower cost of their constituent elements and (v) their lower thermal conductivity. Nonetheless, organic materials also display various drawbacks, including reduced Seebeck coefficients ($S$) and electrical conductivities ($\sigma$), ultimately resulting on average in lower thermoelectric performances. The development of higher performing organic thermoelectric (OTE) materials is thus imperative to promote their wider adoption.

While electrical conductivities $>1000$ S cm$^{-1}$ and power factors ($PF$) $>100$ $\mu$W m$^{-1}$ K$^{-2}$ have been achieved for several p-type organic semiconductors, even the highest performing n-type polymers lag behind these values. This performance disparity presents a significant issue, since maximizing the energy conversion process in a thermoelectric generator necessitates a balanced performance of both p- and n-type components. Developing new n-type polymers with improved thermoelectric performances and formulating structure-property relationships are therefore of utmost importance.

Currently, the most widely explored n-type polymers for OTE are naphthalenetetracarboxylic diimide (NDI) based polymers, specifically N2200. In thermoelectric devices, N2200 affords $\sigma$ in the range of $10^{-3}$ S cm$^{-1}$ and $PF$s in the order of $10^{-2}$ $\mu$W m$^{-1}$ K$^{-2}$. The modest performance of N2200 is typically ascribed to: (i) its poor miscibility with the employed dopant and (ii) the strong localization of its lowest
unoccupied molecular orbital (LUMO), and hence the polaron on the NDI fragment, which arises from a combination of the large dihedral angle between the NDI and bithiophene (T2) moieties and the poor-electron accepting abilities of the T2 unit.\textsuperscript{17,19} The potential unsuitability of employing donor-acceptor (D-A) polymer backbones for OTEs has also been demonstrated in a related set of studies on p-type OTE materials, in which a D-A polymer backbone was compared to its all-donor analogue.\textsuperscript{22} The results obtained indicate that the D-A structure poses an obstacle to efficient doping, with the acceptor moiety being inactive for p-type doping. In an analogous fashion, one can envisage that this concept is likely to also apply to when D-A polymers are employed as n-type OTE materials, where the donor units will be inactive for n-type doping. With this in consideration, conjugated ladder type polymers that exhibit an all-acceptor polymer backbone, seem to be particularly attractive for n-type OTE, especially when considering: (i) their excellent thermal stability rendering them ideal candidates for thermoelectric applications, where thermal stability is crucial.\textsuperscript{15,19,23,24} (ii) The presence of electron-withdrawing carbonyl groups in the conjugated polymer backbone is beneficial as they contribute to reducing the LUMO energy, thus rendering the n-type doping of these materials thermodynamically more favourable.\textsuperscript{15,24,25} (iii) Their highly rigid conjugated polymer backbones facilitate polaron delocalization, consequently aiding charge carrier transport.\textsuperscript{19}

Although the performance of ladder type polymers for n-type thermoelectric applications have improved considerably in recent times and can incur PF values on the order of $10^0 \text{ - } 10^1 \text{ μW m}^{-1} \text{ K}^{-2}$, the elucidation of structure-property relationships of conjugated ladder type polymers for n-type OTE has remained scarce in the literature, with only few studies evaluating the effects of rational chemical modification in terms of device performance.\textsuperscript{15,24,26} To provide further insights into the design of high-performance n-type OTE semiconductors we have investigated the modulation of the aromatic core size of a fused lactam polymer backbone to tune the thermoelectric performance. This involved synthesizing three fused acene
containing polymers formed by the aldol condensation of bis-isatin and bis-oxindole monomers, specifically N-N, A-N and A-A, with their structures illustrated in Figure 1. Tuning the acene core size was deemed as a particularly interesting molecular engineering strategy, given that electron polaron binding energies and hence the charge carrier transport abilities of organic semiconductors are dependent on the size and rigidity of the constituent acene core, and the length of the acene itself can tune the LUMO by varying the spacing along the backbone of the electron withdrawing lactam units.27

![Chemical structures of the rigid polymers investigated within this study.](image)

**Figure 1.** Chemical structures of the rigid polymers investigated within this study.

**Polymer Synthesis**

The syntheses of the bis-oxindole and bis-isatin monomers followed a general strategy reported in the literature.25 For the bis-oxindole monomers, this involved acylation of the corresponding aryl diamine with lauroyl chloride, followed by reduction of the resulting amide with lithium aluminum hydride to the analogous amine. The amine containing aryl species was subsequently reacted with chloroacetyl chloride followed by an intramolecular Heck-type cyclisation to yield the desired bis-oxindole. A more detailed explanation of the synthetic procedures can be found in the supporting information (S.I.).

The synthesis of the bis-isatin monomers on the other hand was based on a Martinet isatin approach. Specifically, this involved reacting the same aryl diamine starting material employed for the bis-oxindole synthesis with diethyl ketomalonate followed by alkylation with
the desired alkyl iodide. The polymers N-N, A-N and A-A were ultimately synthesized by acid catalyzed aldol polycondensation between the enolizable carbonyl unit of the bis-oxindole monomers and the electrophilic carbonyl unit of the corresponding bis-isatin co-monomers. This polymerization approach offers numerous advantages compared to the traditional transition-metal catalyzed one, as it does not necessitate the use of expensive transition metal catalysts such as palladium and it does not require the formation and use of highly toxic organostannane coupling partners, such as those required for Stille cross-couplings.\textsuperscript{23,25} Ultimately, the resulting polymers were obtained in high molecular weights, with $M_n > 50$ kDa, which is often a pre-requisite for high-performance materials in organic electronic applications.\textsuperscript{28,29}

**Polymer Characterization**

The energy levels of the polymers were investigated through a combination of low energy inverse photoemission spectroscopy (LE-IPES), ultraviolet photoelectron spectroscopy (UPS) and UV-Vis spectroscopy and are summarized in Table 1. LE-IPES, UPS and UV-vis spectroscopy were employed to determine the electron affinity (EA), ionization potential (IP) and optical gaps ($E_g$) of the polymers respectively, see Figure S1 and Figure 2. The UPS and LE-IPES spectra onsets were assigned as $2\sigma$ from the leading-edge Gaussian fitted peak.\textsuperscript{30–32} As shown in Table 1, all three polymers exhibited a similarly small $E_g$, while the EA of the polymers became progressively shallower, moving from 3.94 eV to 3.72 eV, upon increasing the size of the aromatic core in the polymer backbone, \textit{i.e.} upon going from an all naphthalene to a mixed naphthalene-anthracene to an all anthracene polymer backbone. This was attributed to the effective dilution of the electron withdrawing properties of the four lactam moieties per polymer repeat unit, consequently rendering the larger anthracene containing systems less electron deficient compared to their naphthalene counterparts. The IPs extracted from the HOMO region of the UPS spectra for the three semiconductors displayed the same trend as
their EAs, with the all naphthalene-based polymer, N-N, showing the largest IP and the all anthracene-based polymer, A-A, possessing the smallest IP, indicating that the orbital electron densities are strongly determined by the electron withdrawing properties of the lactam groups.

Table 1. Summary of the energy levels and optical properties of the polymers under investigation.

<table>
<thead>
<tr>
<th>Polymer</th>
<th>IP (eV)(^a)</th>
<th>EA (eV)(^b)</th>
<th>(\lambda_{\text{max, film}}) (nm)</th>
<th>(E_g) (eV)(^c)</th>
</tr>
</thead>
<tbody>
<tr>
<td>N-N</td>
<td>5.34</td>
<td>3.94</td>
<td>915</td>
<td>1.04</td>
</tr>
<tr>
<td>A-N</td>
<td>5.29</td>
<td>3.83</td>
<td>1039</td>
<td>1.03</td>
</tr>
<tr>
<td>A-A</td>
<td>5.18</td>
<td>3.72</td>
<td>1064</td>
<td>1.03</td>
</tr>
</tbody>
</table>

\(^a\) Extracted from the HOMO region of the UPS spectrum.  
\(^b\) Determined from LE-IPES.  
\(^c\) Calculated from the onset of absorption in thin film samples.

UV-Vis-NIR absorption spectroscopy was conducted on both pristine and doped thin-film samples of the three semiconductors. The corresponding UV-Vis absorption spectra can be found in Figure 2, where in the pristine state, all polymers exhibited two main absorption peaks, one with an absorption onset around 1200 nm and one with an absorption onset around 590 nm. Given that the higher energy transition occurred at energies that were close to two times in magnitude compared to the lower energy absorption, the two transitions were attributed to the \(S_0\) to \(S_1\) and \(S_0\) to \(S_2\) optical transitions respectively. The UV-Vis absorption profiles of the three semiconductors also showed a significant difference in terms of vibronic features. In fact, the absorption profile of N-N displayed a maximum absorption wavelength \(\lambda_{\text{max, film}}\) at 915 nm and no well-resolved fine structure. On the other hand, both anthracene containing polymers, A-N and A-A, demonstrated more resolved fine structures with A-N and
A-A displaying low energy shoulders, which in turn resulted in a red-shift of their thin film absorption maxima to 1039 nm and 1064 nm respectively.

Addition of 25 mol% dopant, specifically 4-(2,3-dihydro-1,3-dimethyl-1H-benzimidazol-2-yl)-N,N-dimethylbenzenamine (N-DMBI), was used to gain insights into the doping process of the polymers. N-DMBI was chosen to solution dope the polymers, thus rendering the doping process compatible with low cost roll-to-roll printing techniques. As highlighted in Figure 2, introduction of N-DMBI in each polymer film resulted in the appearance of a new absorption feature with an absorption maximum at approximately 1900 nm, which we ascribed to a charged species of the polymers. Given that the maximum absorption wavelength of this optical transition remained unchanged at the various doping levels, see Figure SXXX, we tentatively attributed this transition to the polaronic species of the various semiconductors.

Figure 2. UV-Vis-NIR thin film absorption spectra of the pristine and doped a) N-N, b) A-N, c) A-A, and normalized doped absorption spectra of d) N-N, e) A-N and f) A-A.
The thermal properties of the polymers were investigated by both thermogravimetric analysis (TGA) and differential scanning calorimetry (DSC). The TGA and DSC traces of \( \text{N-N} \), \( \text{A-N} \) and \( \text{A-A} \) can be found in Figures S2-S5 in the S.I. All of the polymers displayed excellent thermal stabilities showing no signs of decomposition up to 360 °C, thus suggesting their suitability for thermoelectric applications. Moreover, the DSC traces recorded for all of the polymers were featureless, highlighting the absence of any significant morphological changes upon heating or cooling of the samples.

To gain further insights into the morphological properties and the relative degree of order of the various polymers, grazing-incidence wide-angle X-ray scattering (GIWAXS) was performed on polymer films cast on silicon substrates. The two-dimensional scattering patterns and 1-dimensional line profiles are illustrated in Figure 3.
Figure 3. GIWAXS data of the three polymers: two-dimensional scattering patterns of a) N-N, b) A-N, c) A-A. (d) Comparison of the azimuthally integrated one-dimensional scattering profiles recorded for the three polymers. Profiles offset vertically for clarity.

As shown in Figure 3, all polymers exhibited a semi-crystalline microstructure with both lamellar stacking and π-stacking peaks evident. Despite having identical side chains, the lamellar stacking peaks of the three polymers appeared at slightly different values of $Q$, corresponding to different lamellar stacking distances. For N-N the (100) peak appeared at 2.29 nm$^{-1}$, corresponding to a d-spacing of 27.5 Å. The (100) peak of A-N in comparison occurred at 2.25 nm$^{-1}$ (corresponding to a d-spacing of 28.0 Å) while the (100) peak of A-A was recorded at 2.44 nm$^{-1}$ (corresponding to a d-spacing of 25.8 Å). This indicates that the A-A polymer had the shortest lamellar stacking distance which is likely afforded by the longer backbone repeat unit distance, which in turn may allow for some degree of interdigitation or space-filling of the side chains. The films also exhibited differences in texture: the (100) peak of N-N appeared largely in-plane (along $Q_{xy}$) while the (100) peak of A-A appeared predominantly out-of-plane (along $Q_z$). The A-N polymer shows a somewhat intermediate character suggesting a transition from a predominantly face-on stacking for N-N to a predominantly edge-on stacking for A-A. These changes in texture are more obvious from the horizontal and vertical line profiles, see Figure SXXX in the S.I. While this could be attributed to an intrinsic material property, an alternative possibility, corroborating previous literature reports, is that the progressively lower solubility of the polymers in the processing solvent upon acene core expansion, leads to pre-aggregation in solution, forming lamella sheets, which deposit in the plane of the substrate, with a preferential edge-on deposition of the backbone, orthogonal to the lamella.$^{34,35}$
The $\pi$-$\pi$ stacking peak for the three materials occurred at 17.4 nm$^{-1}$ for N-N, 17.3 nm$^{-1}$ for A-N, and 17.6 nm$^{-1}$ for A-A, corresponding to similar $\pi$-$\pi$ stacking distances of $\sim$3.6 Å for all polymers. It is noted that the A-N polymer exhibits broader lamellar stacking peaks indicating a smaller crystallite size. It is noted that the A-N polymer exhibits broader lamellar stacking peaks indicating a smaller crystallite size and/or increased lattice disorder. In particular, the full-width-at-half-maximum (FWHM) of the in-plane (100) peak were 0.018 Å$^{-1}$, 0.033 Å$^{-1}$, 0.021 Å$^{-1}$ for N-N, A-N, and A-A, respectively.

To complement the experimentally recorded data, density functional theory (DFT) calculations were carried out on tetramers of the various polymers employing an optimally tuned ωB97X-D functional and 6-31G* as the basis set. The DFT optimized structures of the three tetramers are shown in Figure S9, S11 and S13 in the S.I. As is common in the field, the long solubilizing alkyl chains were replaced by the shorter methyl groups to simplify the simulations.

First, geometry optimizations of the tetramers were performed, revealing that the anti configuration, i.e. the one in which the carbonyl moieties of neighboring bis-isoiindigo units are oriented in opposite directions, to be the thermodynamically most favorable configuration, see Figure S6 in the S.I. Closer evaluation of the 120-180° region of the torsional potential energy surface, see Figure 4, showed an energetic minimum at 165°, thus indicating the almost planar configuration assumed by the conjugated polymer backbone for the three polymers. Also note the relatively shallow torsional potential energy surface (PES) incurred at 165° by each of the three polymers, which enables dihedral angle fluctuations of ±15° at room temperature. This feature, in combination with intermolecular packing interactions between neighboring polymer chains is likely to enable the polymers to assume an even more planar configuration in the solid state, thus benefiting orbital overlap and in turn also polaron delocalization and intermolecular charge transport of these materials.
Single point DFT calculations on the optimized geometries were performed to determine the MO distribution of the neutral polymer LUMO and the singly occupied molecular orbital (SOMO) of the anionic polymer over the eight acene fragments comprising the tetramers of the various polymers. As shown in Figure 4 the neutral polymer LUMOs were primarily distributed on the central four acene units of all the polymers. The slight difference in the shape of the MO contribution trace of A-N compared to the ones of N-N and A-A was due to the mixed naphthalene and anthracene cores present within the A-N polymer. As seen in Figure 4, the introduction of two different acene cores resulted in an asymmetric LUMO distribution of the A-N polymer, which in turn were due to the stronger contributions from the lactam groups in the central two naphthalene cores to the LUMO in comparison to those in the anthracene cores. These findings therefore indicate that the naphthalene bis-oxindole unit had a more electron deficient character compared to its anthracene counterpart, thus corroborating the findings from UPS and LE-IPES.

We envisaged the SOMO of the anionic polymer distribution to be of particular interest given its analogy to the electron polaron of the corresponding polymers. The MO distribution of the anionic polymer SOMO showed more localized character than the neutral LUMO, but significant differences were observed across the three polymers, see Figure 4, with the N-N polymer showing the broadest distribution and the A-A polymer the narrowest one. To better quantify the width of the MO distribution curve and use it as an indicator of the delocalization of the anionic polymer SOMO and hence polaron, we calculated the full width half maximum (FWHM) of the MO distribution curves. The FWHM computed for the N-N, A-N and A-A polymers were 2.4 fragments, 2.3 fragments and 2.0 fragments respectively, thus revealing that the anionic polymer SOMO of N-N to be the most delocalized and that of the A-A polymer to be the least delocalized.
Hirshfeld atomic charges of each atom of the neutral polymer were subtracted from the equivalent atomic charges of the anionic polymer, leading to a visualization of where the extra charge upon reduction was found along the polymer chain. Within the fragment analysis, there is strong agreement with the MO contributions. Plotting on an atom-by-atom basis, see Figure S16 in the S.I., shows that most of the charge is located on only a few atoms, although the same trends in charge distribution can be observed. Interestingly, the mixed A-N polymer shows two similar environments bearing similar amounts of charge. Most of this charge is stabilized by the bridging C-C double bond carbon atoms between fragments, and the carbonyl groups, see Figure S17 in the S.I. The comparison between N-N and A-A is also interesting, in that the fragment approach suggests that the N-N polymer has a greater degree of delocalization. Turning to a distance comparison, A-A shows similar delocalization lengths to N-N, but N-N spreads the charge over more repeat units, and over more of the more stabilizing C=C and C=O groups. Thus, in addition to changes in energy levels relevant to electronic doping, the change from naphthalene to anthracene also spaces out the atoms capable of stabilizing the excess charge, leading to localization on only a few groups. Consequently, this suggested the polaron in the N-N polymer to be the most delocalized and hence N-N to be most suited towards thermoelectric applications, given that previous studies have indicated a strong relationship between polaron delocalization and electrical conductivity.\textsuperscript{17}

**Figure 4.** a) Torsional potentials around the center most C=C bond in the neutral tetramers of N-N, A-N and A-A focusing on the 120-180° region. Computed MO distributions of the b)
neutral LUMO and c) anionic polymer SOMO for the tetramers of N-N, A-N and A-A. The MO distribution traces of the neutral LUMO of N-N and A-A are overlapping.

**Figure XXX.** Output and transfer curves recorded for N-N, A-N and A-A.

Lastly, the energy levels and optical properties of the semiconductors were computed. The IPs calculated for N-N, A-N and A-A were 5.34 eV, 5.14 eV and 5.11 eV thus reflecting the trend recorded in the UPS measurements. A good fit between the experimental and computational trends obtained for the EAs of the polymers was also observed with the simulated EA for N-N being the largest (3.21 eV), for A-N being in the middle (3.16 eV) and for A-A being the smallest (3.11 eV).

Having established the suitability of the series of ladder type semiconducting polymers, their electrical conductivity, \( \sigma \), which mathematically is given in equation 3 was investigated next.

\[
\sigma = ne\mu
\]  
(3)

Where \( n \) is the number density of charge carriers, \( e \) the elementary charge and \( \mu \) the charge carrier mobility.

As highlighted in Figure 5 the electrical conductivity for each polymer is lowest in the absence of any N-DMBI. However, increasing the N-DMBI concentration resulted in an increase in the conductivity with \( \sigma \) increasing over four orders of magnitude for each polymer. The maximum electrical conductivity (\( \sigma_{\text{max}} \)) recorded for N-N, A-N and A-A were 0.65 S cm\(^{-1}\), 0.26 S cm\(^{-1}\) and 0.018 S cm\(^{-1}\) respectively. The recorded trend in \( \sigma_{\text{max}} \) therefore is consistent
with the trend in the electron mobility ($\mu_e$) for the three polymers, measured in organic field effect transistor (OFET) devices that featured a top-gate bottom-contact (TGBC) architecture. The OFET characterization data for each polymer can be found in Figure S18 the S.I. The electron mobilities recorded in the linear ($\mu_{e,\text{lin}}$) and saturation ($\mu_{e,\text{sat}}$) regimes for the three polymers were 0.20 cm$^2$ V$^{-1}$ s$^{-1}$ and 0.33 cm$^2$ V$^{-1}$ s$^{-1}$ for N-N, 0.15 cm$^2$ V$^{-1}$ s$^{-1}$ and 0.23 cm$^2$ V$^{-1}$ s$^{-1}$ for A-N and 0.05 cm$^2$ V$^{-1}$ s$^{-1}$ and 0.07 cm$^2$ V$^{-1}$ s$^{-1}$ for A-A respectively, thus highlighting that N-N and A-N had comparable mobilities, while further increasing the acene core size was detrimental for charge carrier transport.

Figure XXX. Organic field effect transistor output a) N-N, b) A-N and c) A-A and transfer curves for d) N-N, e) A-N and f) A-A respectively.

Comparing the differences recorded in the $\sigma_{\text{max}}$ with the differences recorded in the $\mu_e$ for the polymers lead to the conclusion that the difference in the polymers’ $\mu_e$ is not sufficient to fully explain the difference in $\sigma_{\text{max}}$. In fact, the larger difference in $\sigma_{\text{max}}$ suggests that
increasing the acene core size also results in lower charge carrier densities, \( n \), generated during the doping process. Finally, the recoded \( \sigma_{\text{max}} \) trend also followed the trend in the simulated anionic polymer SOMO delocalization, whereby increasing the anionic polymer SOMO delocalization led to polymers with a higher \( \sigma_{\text{max}} \). This in turn further supported previous literature evidence of a correlation between the degree of delocalization of the electron polaron and the electrical conductivity of materials.\(^{17}\)

**Figure 5.** a) Electrical conductivities, b) Seebeck coefficients and c) power factors recorded for N-N, A-N and A-A as a function of N-DMBI ratio employed.

Next, the thermopower of the three semiconductors was measured. For all the three members of the series negative thermopower values were obtained, hence indicating that
electrons were the majority carrier within each of the polymers. The Seebeck coefficient for N-N, A-N and A-A was highest at a dopant ratio of 3 mol% and decreased progressively upon increasing the dopant ratio. At each N-DMBI ratio, N-N and A-A displayed the lowest and highest $S$ respectively.

As anticipated and highlighted in Figure 5, the evolution of $\sigma$ and $S$ as a function of dopant ratio followed an opposite trend, thus signifying that the maximum power factor for the polymers was obtained at a dopant concentration that would best balance the two quantities. The maximum $PF$s of the three semiconductors were recorded at different dopant concentrations with N-N affording the highest $PF$ of 3.2 $\mu$W m$^{-1}$ K$^{-2}$ at 9 mol% N-DMBI concentration, A-N a $PF$ of 1.6 $\mu$W m$^{-1}$ K$^{-2}$ at 15 mol% N-DMBI content and A-A a $PF$ of 0.25 $\mu$W m$^{-1}$ K$^{-2}$ at 25% dopant ratio. The $PF$ recorded for N-N and A-N are amongst the highest recorded for n-type OTE materials to date, while the $PF$ recorded for A-A is still higher compared to the thoroughly studied and optimized N2200 polymer.$^{14-16,18,20,24}$

Table 2. Organic field effect transistor and thermoelectric performance summary of the polymers under investigation.

<table>
<thead>
<tr>
<th>Polymer</th>
<th>$\mu_{e,lin}^{a}$ (cm$^2$ V$^{-1}$ s$^{-1}$)</th>
<th>$\mu_{e,sat}^{a}$ (cm$^2$ V$^{-1}$ s$^{-1}$)</th>
<th>$\sigma_{max}$ (S cm$^{-1}$)</th>
<th>$PF_{max}$ (µW m$^{-1}$ K$^{-2}$)</th>
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<tbody>
<tr>
<td>N-N</td>
<td>0.20</td>
<td>0.33</td>
<td>0.65</td>
<td>3.2</td>
</tr>
<tr>
<td>A-N</td>
<td>0.15</td>
<td>0.23</td>
<td>0.26</td>
<td>1.6</td>
</tr>
<tr>
<td>A-A</td>
<td>0.05</td>
<td>0.07</td>
<td>0.018</td>
<td>0.25</td>
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</table>

$^{a}$Obtained from TGBC OFET measurements.

Conclusion

In summary, three new n-type fused lactam semiconducting polymers only differing in the relative size of their constituent acene cores were synthesized for thermoelectric and
transistor applications. Compared to traditional transition-metal catalyzed polymerization reactions for conjugated polymers, the materials developed herein were obtained via a convenient transition-metal free aldol polycondensation reaction, thus avoiding the use of expensive palladium-based catalysts and any highly toxic organometallic synthetic intermediates. TGA measurements indicated excellent thermal stability of each polymer, with none of the materials showing any sign of decomposition up to 360 °C. Experimental and computational energy level analysis of the three polymers on the other hand demonstrated that reducing the central acene core size from two anthracene (A-A), to mixed naphthalene-anthracene (A-N) and two naphthalene cores (N-N) progressively resulted in larger EAs, thereby leading to an increasingly more favorable and efficient doping process when employing N-DMBI as the dopant. In parallel, both OFET mobility data and DFT simulations also suggested the benefits of acene core contraction on the thermoelectric performance, with the N-N polymer affording the highest electron mobility and the most delocalized electron polaron and the A-A polymer incurring the lowest values. Ultimately, these concepts were clearly reflected in the thermoelectric performance data recorded for the polymers with N-N, A-N and A-A affording maximum electrical conductivities and power factors of 0.65 S cm\(^{-1}\) and 3.2 μW m\(^{-1}\) K\(^{-2}\), 0.26 S cm\(^{-1}\) and 1.6 μW m\(^{-1}\) K\(^{-2}\) and 0.018 S cm\(^{-1}\) and 0.25 μW m\(^{-1}\) K\(^{-2}\) when doped with N-DMBI respectively. The PF recorded for N-N and A-N are thus amongst the highest reported in the literature for n-type polymers. Importantly, the results reported in this study highlight that modulating the size of the central acene ring is a highly effective molecular design strategy to optimize the thermoelectric performance thus also providing new insights into the molecular design guidelines for the next generation of high-performance n-type materials for thermoelectric applications.

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